

# SENSORS and TRANSDUCERS



Tadeusz Stepinski, Signaler och system

## \* The Thermal Energy Domain

- Physics
  - » Seebeck effect
  - » Peltier effect
  - » Thomson effect
- Thermal effects in semiconductors
- Thermoelectric sensors
- Thermoresistive sensors



# Thermal Energy Domain - Physics



- \* We are considering thermal transducers that are used for converting thermal information into electrical signals.
- \* Basic mechanisms relevant for our discussion:
  - Seebeck effect
  - Peltier effect
  - Thomson effect
  - Thermoresistance

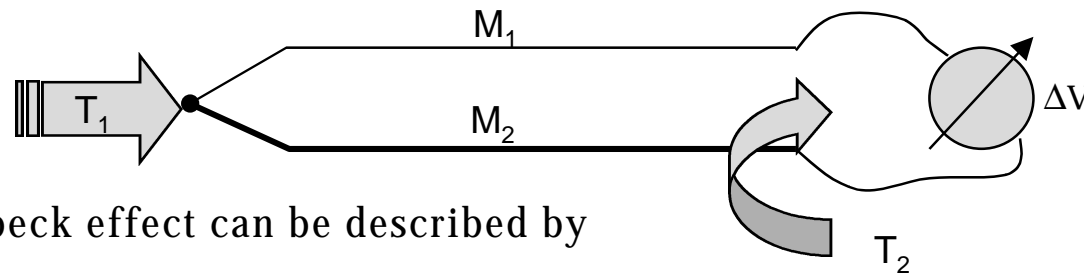


# Thermal Energy Domain - Physics



## \* The Seebeck effect

Generation of electrical voltage due to temperature difference between a weld of two different materials and the other ends of these wires



Seebeck effect can be described by

$$\Delta V = a_s \Delta T$$

where:

$\alpha_s$  ( $\mu\text{VK}^{-1}$ ) - Seebeck coefficient

$\Delta V$  (V) - voltage difference

$\Delta T$  (K) - absolute temperature difference



# Thermal Energy Domain - Physics



- \* Seebeck coefficient describes a bulk effect, determined by the following effects:
  - Temperature difference generates a difference in Fermi level
  - Bandgap distance changes with temperature
  - The gradient of charge carriers changes for  $n$  and  $p$  type as a function of temperature
  - Diffusion coefficient is a function of temperature
  - Charge carriers move from the heated side to cold side - thermodiffusion
  - Electric field will be generated due to the transport of charge carriers
- \* Seebeck effect is used mainly in thermocouples used for temperatures ranging from - 200 to 1600 °C



# Thermal Energy Domain - Physics



## \* Peltier effect

A reverse effect to Seebeck effect, discovered in 1834 by Peltier.

When a current flows through a junction of two different metals heat is dissipated or absorbed towards or from the the environment.

$$Q = -\Pi_{ab} J_{ab}$$

where:  $Q$  (J m<sup>-2</sup>) - dissipated or absorbed heat

$\Pi_{ab}$  (J C<sup>-1</sup>) - Peltier coefficient for a junction with materials  $a$  and  $b$

$J_{ab}$  (C m<sup>-2</sup>) - charge carrier density flowing from  $a$  to  $b$

Relationship between Peltier and Seebeck coefficients (under certain conditions)

$$\Pi_{ab} = a_s T$$

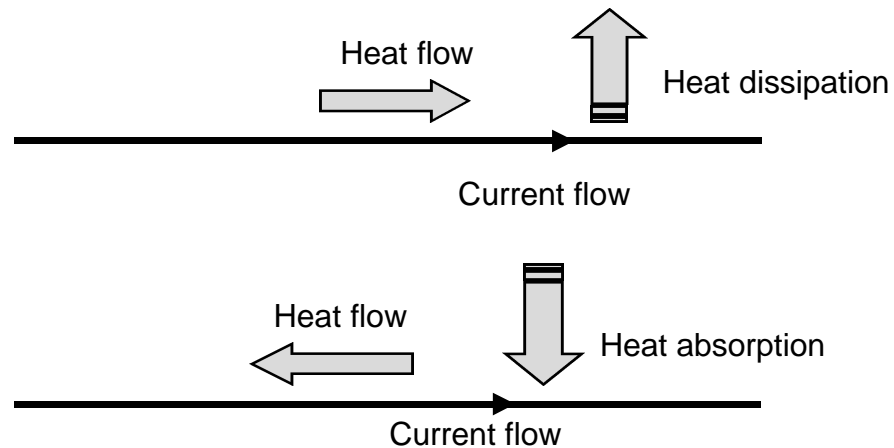


# Thermal Energy Domain - Physics



## \* Thomson effect (reversible)

Current flowing in a wire in which temperature gradient is present shows a heat exchange with its environment.



# Thermal Energy Domain - Physics



## \* Thomson effect

$$Q_{th} = g \cdot J \cdot \Delta T$$

where  $Q_{th}$  (W m<sup>-2</sup>) - heat flow  
 $g$  (VK<sup>-1</sup>) - Thomson coefficient  
 $J$  (Am<sup>-2</sup>) - current density  
 $T$  (K) - temperature

Kelvin proved the following relationship between Seebeck and Thomson coefficients

$$g = T \frac{\partial a_s}{\partial T}$$



# Thermal Energy Domain - Physics



## \* Thermoresistance

Macroscopic description

$$R(T) = R(0) \cdot (1 + AT + BT^2)$$

where:  $R(T)$ ,  $R(0)$  - resistance at temperature  $T$  and  $-273^\circ\text{K}$ , respectively

$A$ ,  $B$  - temperature coefficients

Term  $B$  can be neglected for most materials

Microscopic description

$$S = n \cdot q \cdot m$$

where:

$\sigma$  ( $\Omega \text{ m}$ ) - conductivity

$n$  ( $\text{m}^{-3}$ ) - number of charge carriers per unit volume

$q$  ( $1.6 \cdot 10^{-19} \text{ C}$ ) - specific charge

$\mu$  ( $\text{m}^2\text{V}^{-1} \text{ s}^{-1}$ ) - electron mobility





# Thermal effects in semiconductors



- \* Thermistor = thermal sensitive resistor

Thermistors are composed of sintered ceramic semiconductor and metal oxides - manganese, cobalt, copper and iron

Thermistor resistance

$$r(T) = r(T_0) \cdot \exp[-B \cdot (1/T - 1/T_0)]$$

where  $r(T_0)$  - resistivity at  $T=T_0$   
 $B$  - constant (in the range of 4000K)

Most thermistors have negative temperature coefficient (NTC)

$$a = \frac{dr}{r} = -\frac{B}{T^2}$$



# Review of thermal effects



\* Thermal physical mechanisms used for transducers

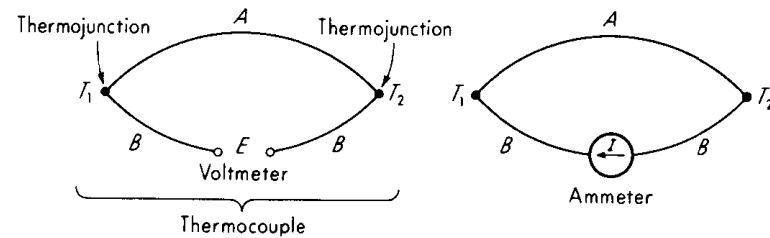
<b>Name of effect</b>	<b>Notation</b>	<b>Macroscopic description</b>
Thermoelectric, Seebec	[th,el,00]	Generation of electrical potential by a joint of two dissimilar conductors
Pyroelectric	[th,el,00]	Change of polarization due to temperature change
Nernst	[th,el,ma]	Generation of electromagnetic field due to temperature gradient
Thermodielectric	[el,el,th]	Change of permittivity of a ferroelectric due to temperature
Thermoconductivity	[el,el,th]	Change of conductivity due to temperature
Thermoluminescence	[th,ra,00]	Emission of radiant energy of certain crystals due to temperature
Curie temperature	[th,ma,00]	Change to paramagnetism of ferromagnetic material at specified temperature
Incandescence	[th,ra,00]	Emission of radiant energy when material is heated
Therochemical	[th,el,00]	Change of structure due to temperature
Electrothermal	[el,th,00]	Generation of heat in a conductor by electric current
Peltier	[el,th, 00]	Generation of temperature difference between two junctions when current passes through them



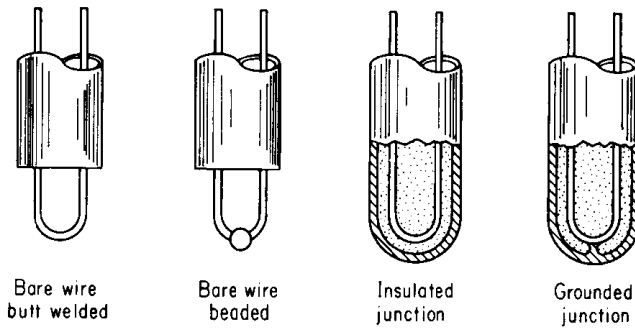
# Thermoelectric sensors



## \* Thermocouples



(a)



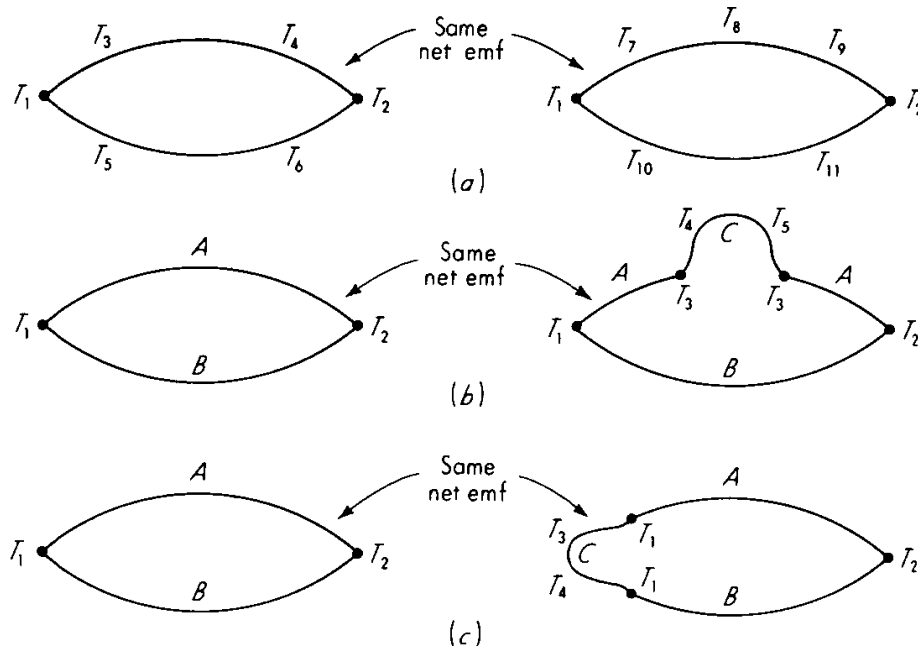
(b)



# Thermoelectric sensors



## \* Thermocouple laws



Thermal emf is unaffected by temperature elsewhere in the circuit

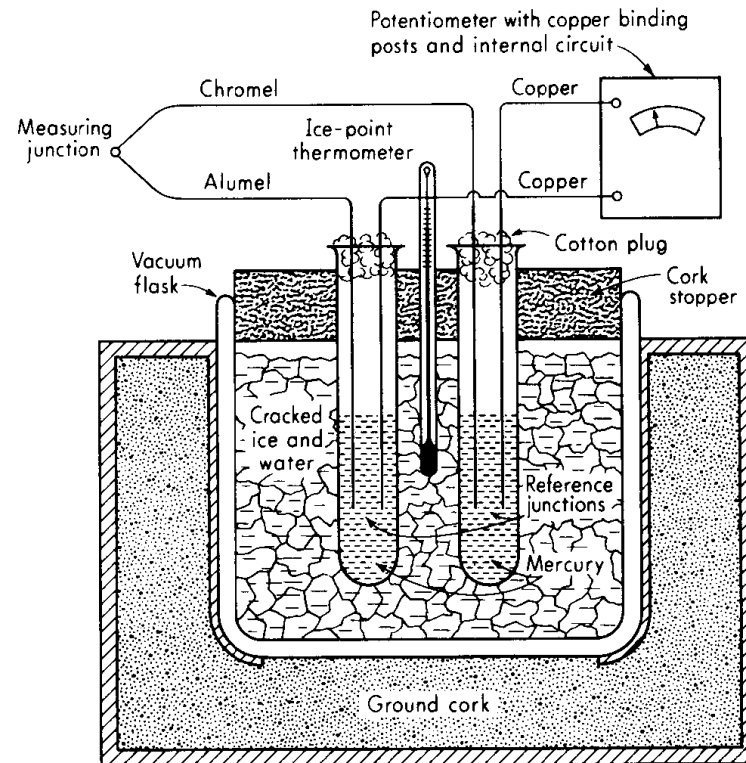
A third homogenous metal C does not affect the emf as long as the new junctions have the same temperatures



# Thermoelectric sensors



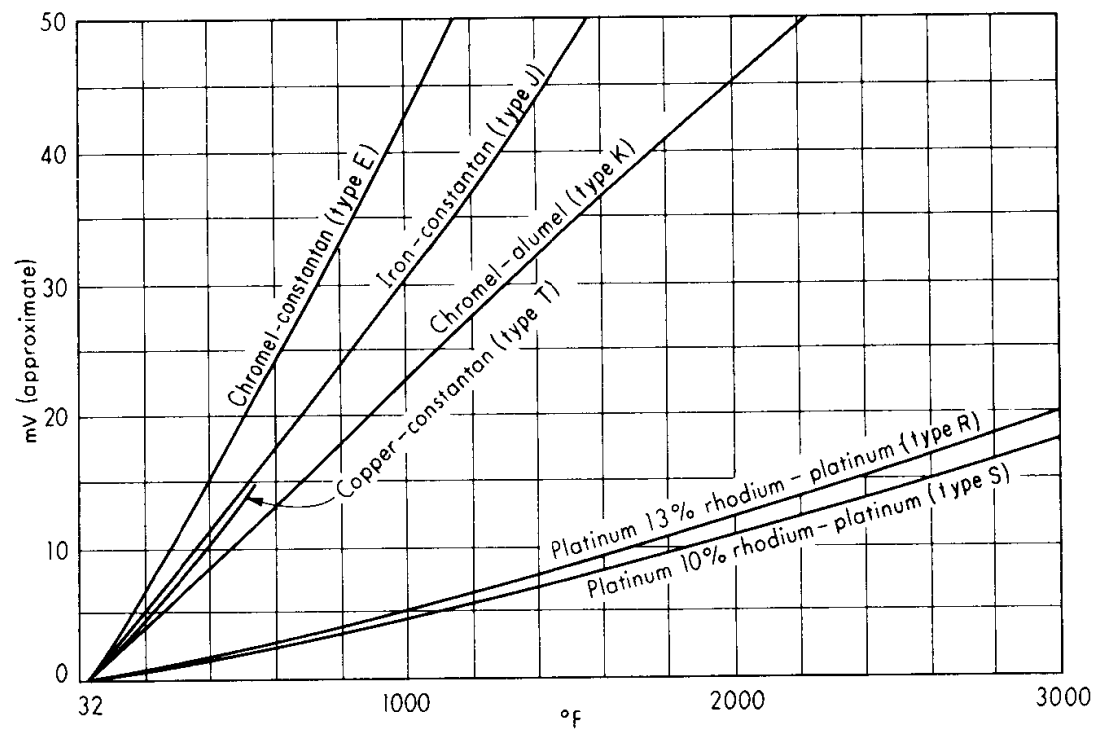
## \* Thermocouples - ice bath for reference junction



# Thermoelectric sensors



## \* Thermocouple - mV output versus temperature



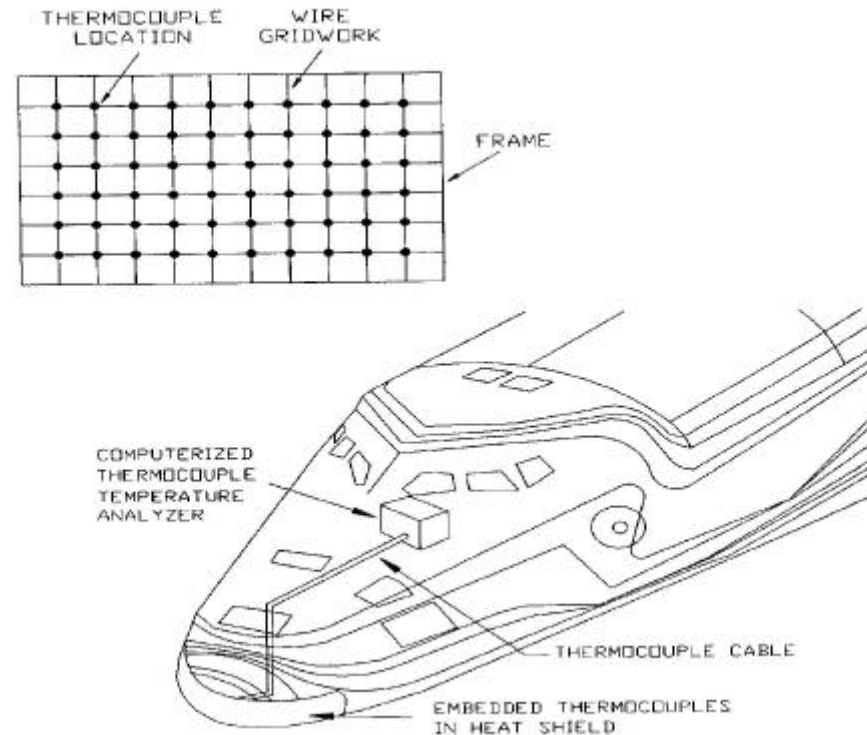
Thermocouple temperature/voltage curves.



# Thermoelectric sensors - applications



- \* Thermocouple grid applied space shuttles frond end

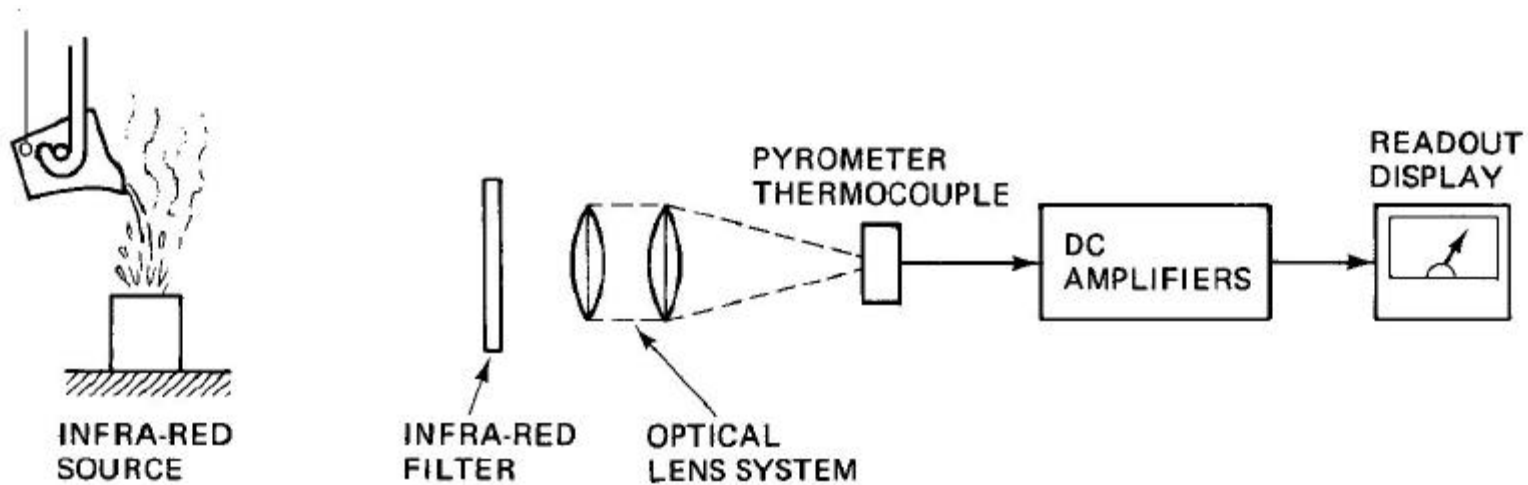


# Thermoelectric sensors - applications



## \* Pyrometer using thermopile circuit

Thermopile - a circuit arranged of a number of thermocouples in series





# Thermoelectric sensors - applications



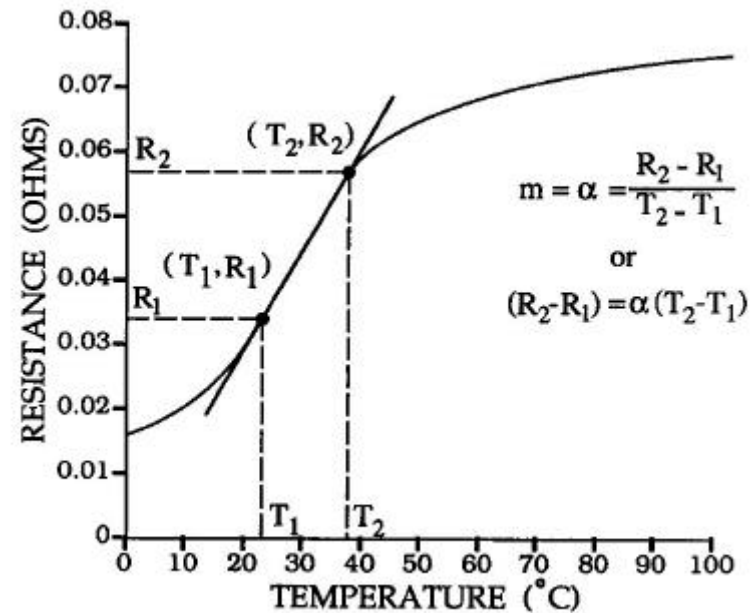
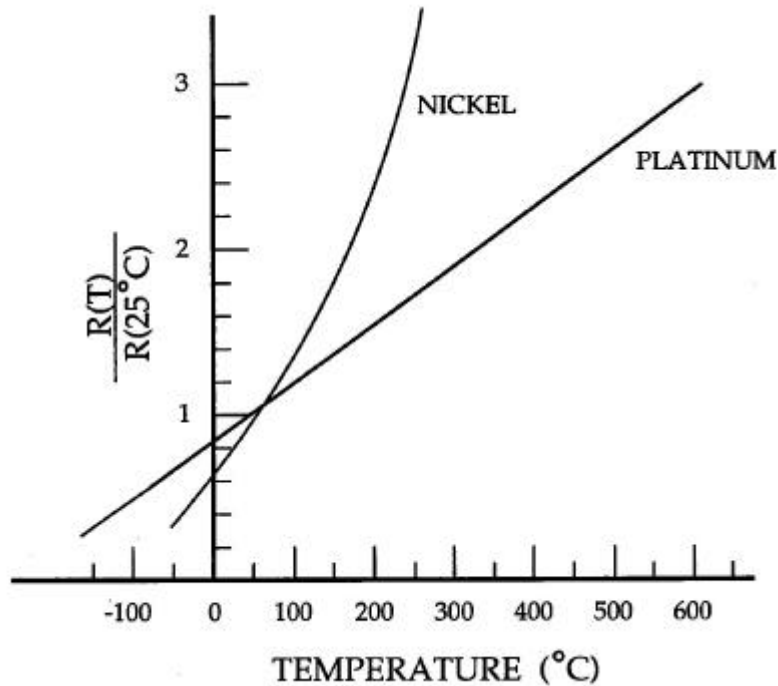
- \* Infrared pyrometer (Omega Eng. Inc.)



# Thermoeresistive sensors



\* Temperature coefficients of metals



Dc resistance vs temperature for platinum



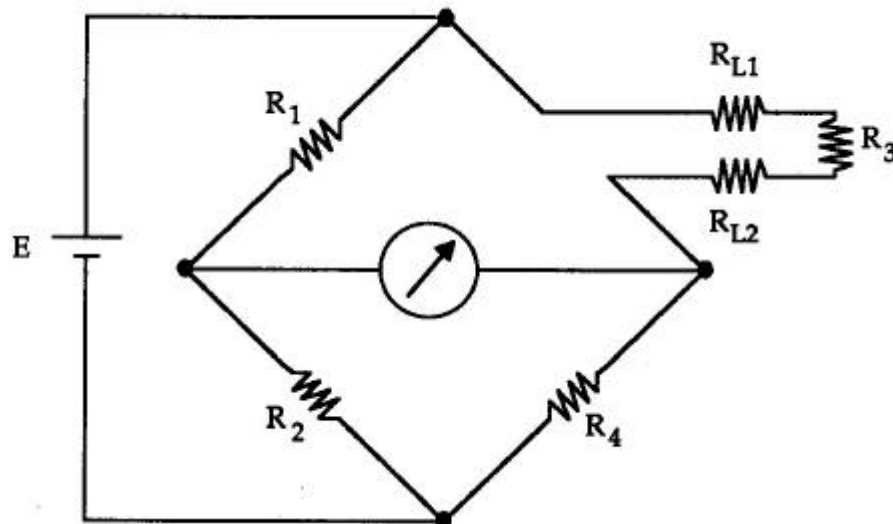
# Thermoeresistive sensors



## \* RTD signa-conditioning circuits

RTD - resistance temperature detector

### ● Two-wire uncompensated RTD circuit



For bridge in balance

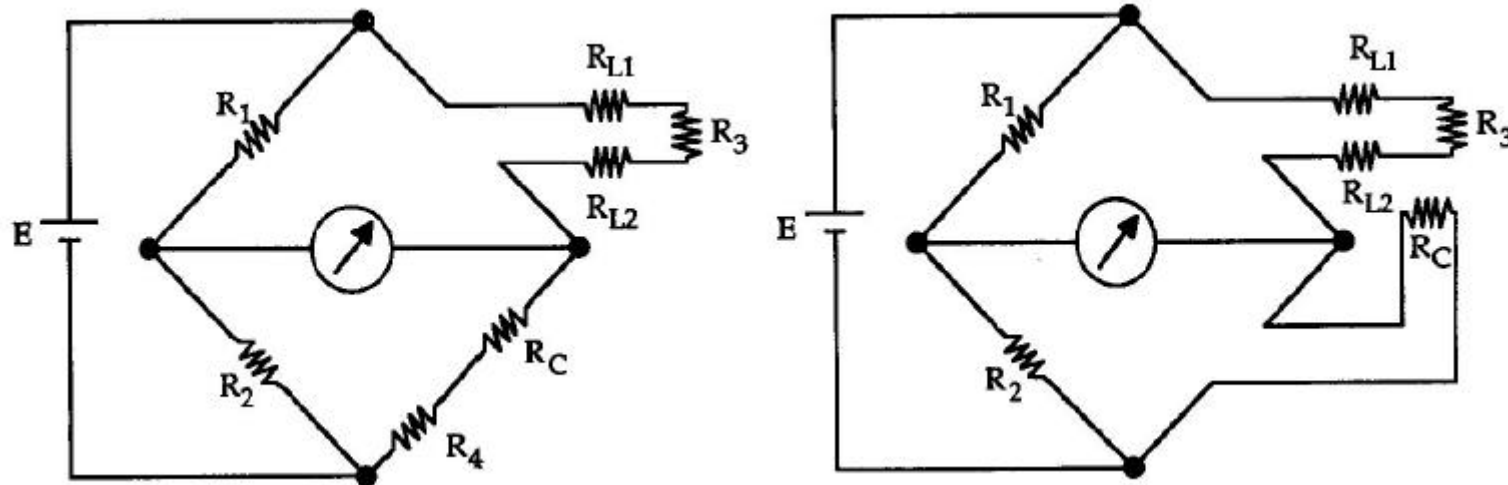
$$\frac{R_1}{R_2} = \frac{R_{L1} + R_{L2} + R_3}{R_4}$$



# Thermoeresistive sensors



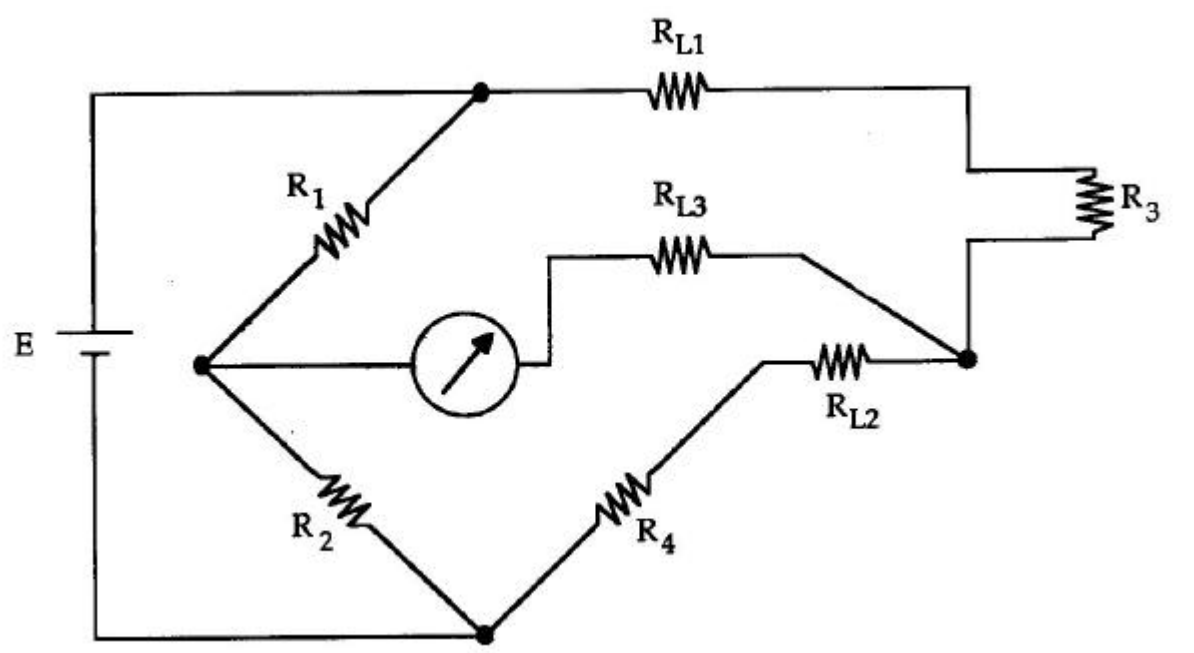
- Two-wire compensated RTD circuit



# Thermoerisistive sensors



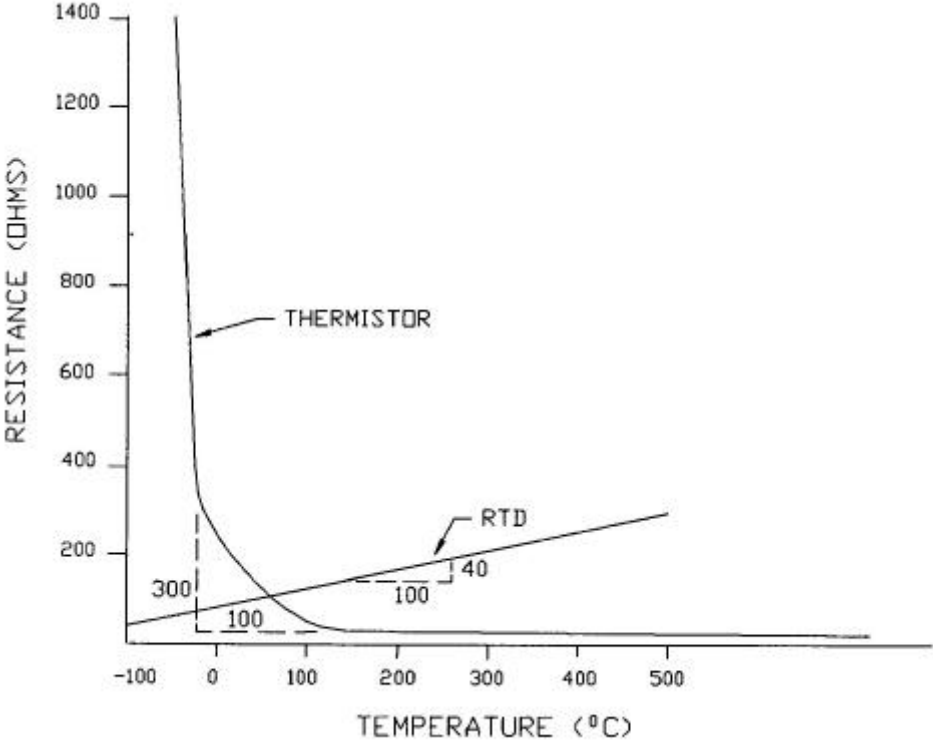
- Three-wire RTD circuit



# Thermoeresistive sensors

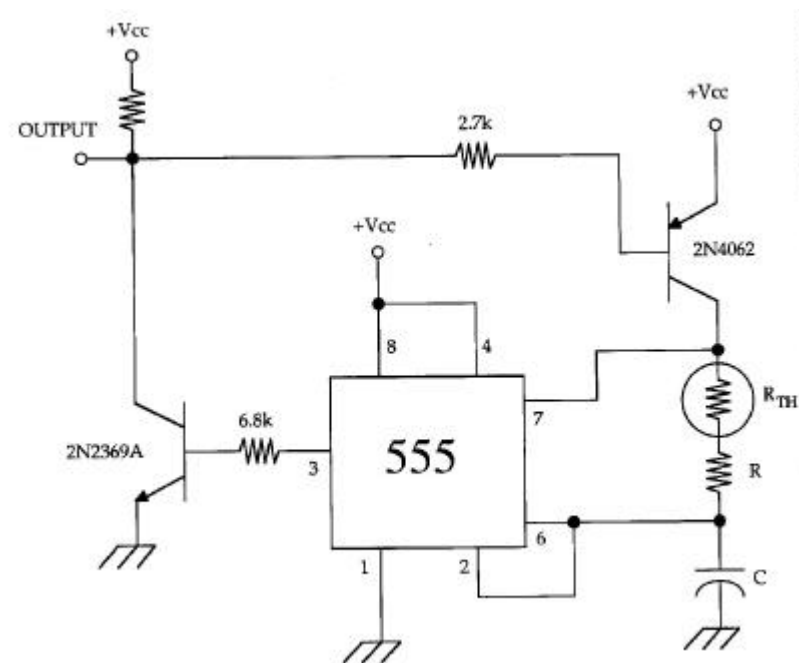


- Thermistor



# Thermoeresistive sensors - applications

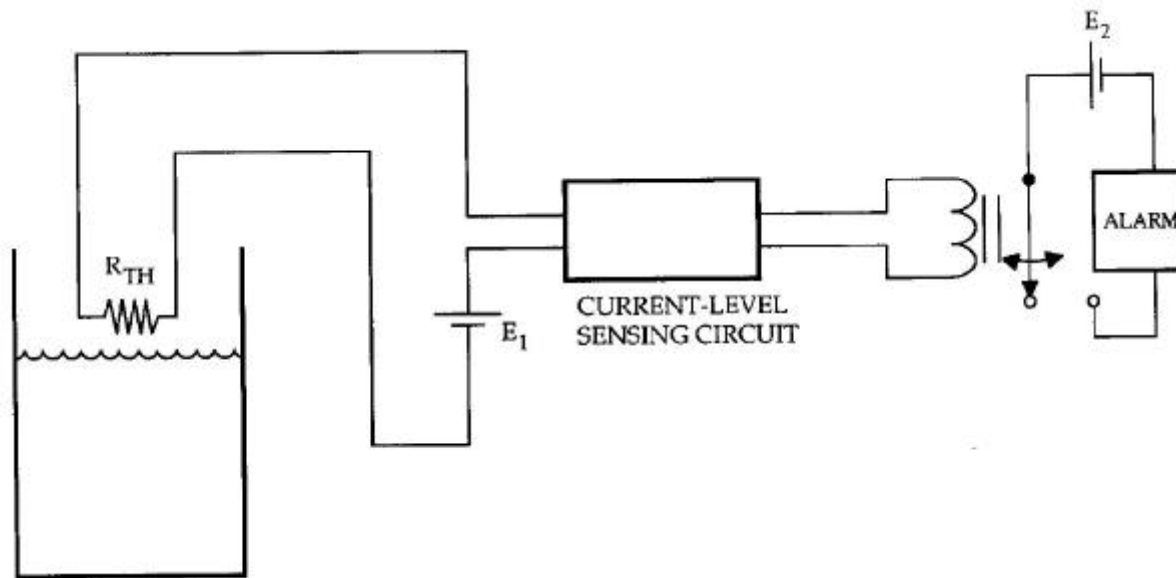
- \* Temperature - frequency converter



# Thermoeresistive sensors - applications



- \* Thermistor used as level indicating device





# Review Questions



- Describe in detail the Peltier, Seebeck and Thomson effects.
- What effects contribute to Seebeck effect?
- What would you think the dc resistance would be for thermocouple? Do you think the resistance would be thousand, hundreds of ohms, or just few ohms?
- What is a thermopile? Where are they used?
- Explain the difference between material having a positive and negative temperature coefficient
- What is the advantage of using a platinum RTD versus one made of nickel? What is the advantage of a nickel RTD?
- Explain the circuit for three-wire RTD and explain its advantages over a standard two-wire uncompensated circuit.

